Elektronische Bauelemente

DTC123YE / DTC123YUA / DTC123YCA

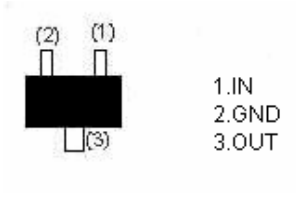
NPN Digital Transistors (Built-in Resistors)

RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

FEATURES

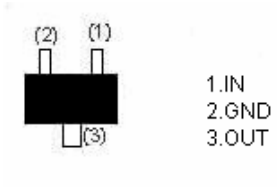
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- Only the on/off conditions need to be set for operation, making device design easy.

DTC123YE (SOT-523)



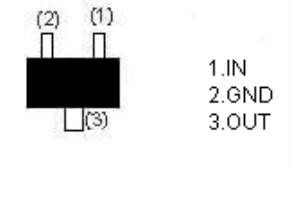
Addreviated symbol：62

DTC123YUA (SOT-323)



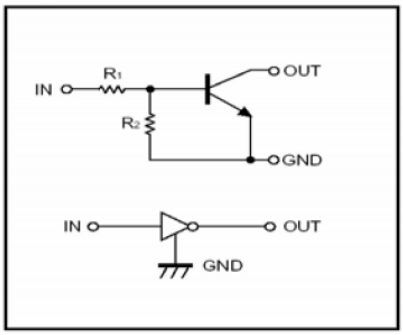
Addreviated symbol：62

DTC123YCA (SOT-23)



Addreviated symbol：62

EQUIVALENT CIRCUIT



ABSOLUTE MAXIMUM RATINGS (T_A=25℃ unless otherwise noted)

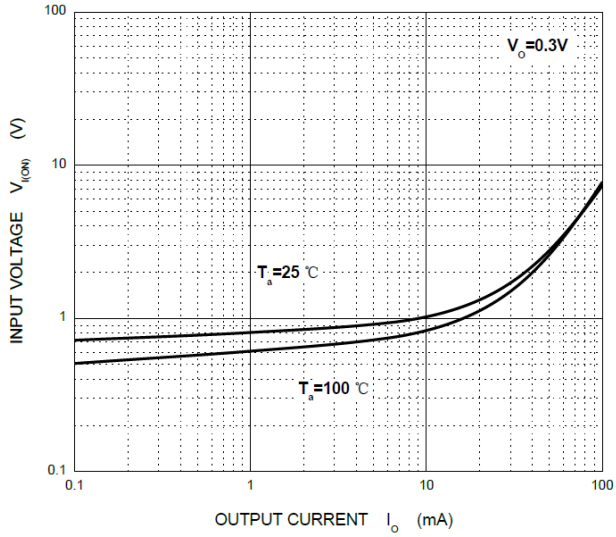
Parameter	Symbol	Limits (DTC123Y□)			Unit
		E	UA	CA	
Supply Voltage	V_{CC}	50			V
Input Voltage	V_{IN}	-5~12			V
Output Current	I_O	100			mA
Power Dissipation	P_D	150	200		mW
Junction and Storage Temperature	T_J, T_{STG}	150, -55~150			℃

ELECTRICAL CHARACTERISTICS (T_A=25℃ unless otherwise noted)

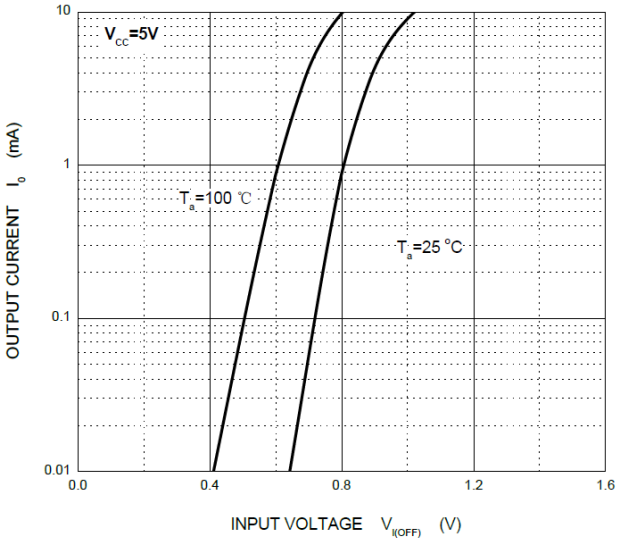
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Input Voltage	$V_{I(off)}$	0.3	-	-	V	V_{CC}=5V, I_O=100μA
	$V_{I(on)}$	-	-	3		V_O=0.3V, I_O=20mA
Output Voltage	$V_{O(on)}$	-	0.1	0.3	V	I_O/I_I=10mA / 0.5mA
Input Current	I_I	-	-	3.8	mA	V_I=5V
Output Current	$I_{O(off)}$	-	-	0.5	μA	V_{CC}=50V, V_I=0
DC Current Gain	G_I	33	-	-		V_O=5V, I_O=10mA
Input Resistance	R_1	1.54	2.2	2.86	KΩ	
Resistance Ratio	R_2 / R_1	3.6	4.5	5.5		
Transition Frequency	f_T	-	250	-	MHz	V_O=10V, I_O=5mA, f=100MHz

CHARACTERISTIC CURVES

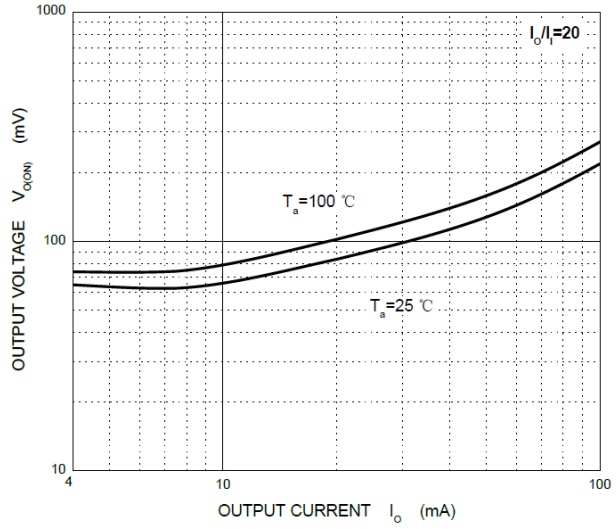
ON Characteristics



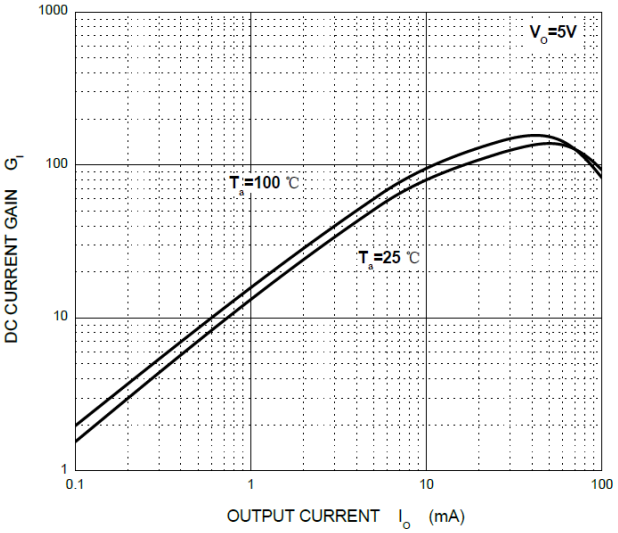
OFF Characteristics



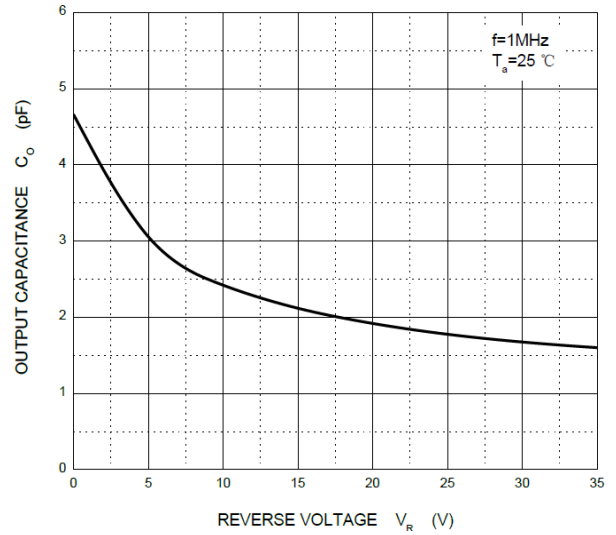
$V_{O(ON)}$ — I_O



G_I — I_O



C_O — V_R



P_D — T_a